## NSN 5961-01-380-7804

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-380-7804 **Inclosure Material:** Metal and plastic **Overall Length:** 1.500 inches **Overall Height:** 0.300 inches **Overall Width:** 1.250 inches **Mounting Facility Quantity: Component Name And Quantity:** 10 semiconductor device diode **Mounting Method:** Threaded hole **Features Provided:** Electrostatic sensitive **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, peak 8th semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 16340-80-00061 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:**